



Military Temperature MEMS Oscillator

Features

- Any Frequency Between 3.5 kHz and 100 MHz Accurate to 6 Decimal Places
- Low Power Consumption of 4.5 mA Typical
- CMOS-Compatible Output
- Industry-Standard Packages: 7.0 mm × 5.0 mm, 5.0 mm × 3.2 mm, 3.2 mm × 2.5 mm, 2.5 mm × 2.0 mm, 2.0 mm × 1.6 mm, 1.6 mm × 1.2 mm
- Operating Temperature to 125°C
- Capable of Surviving 50,000g Shock, with 70g Vibration Resistance

Applications

- Military Applications
- Environmentally Demanding Applications
- Ruggedized Equipment

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Output Frequency	f _{OUT}	3.5k		100M	Hz	—
		-20		+20		Inclusive of initial tolerance at +25°C and
Frequency Stability	f _{STAB}	-25		+25	ppm	variations over operating temperature,
		-50		+50		rated power supply voltage and load.
Aging	£	-5		+5		1st year at +25°C
Aging	f _{AGING}	-1		+1	ppm	After 1st year at +25°C
о <i>и</i> т ,		-40		+125		
Operating Temperature Range	T _{OP}	-40		+105	°C	_
Tange		-40		+85		
Supply Voltage		1.71	1.8	1.98		
	V _{DD}	2.25	2.5	2.75		
		2.52	2.8	3.08	V	<u> </u>
		2.7	3.0	3.3		
		2.97	3.3	3.63		
Ourseast Consumption			4.0	_		No load condition, f = 27 MHz, V _{DD} = 2.0V, 2.8V, 3.0V or 3.3V
Current Consumption	I _{DD}	_	3.0	_	mA	No load condition, f = 27 MHz, V_{DD} = 1.8V
Standby Current			1.5			V _{DD} = 2.0V or 3.3V
Standby Current	ISTD		1.0		μA	V _{DD} = 1.8V, output is weakly pulled down
Duty Cycle	DC	45		55	%	All supply voltage options
Rise Time	t _r	_	0.6	1.2	ns	20% to 80% V_{DD} = 2.5V, 2.8V, 3.0V or 3.3V; C _L = 10 pF
Fall Time	t _f		1.2	2.0	ns	20% to 80% V_{DD} = 1.8V; C_{L} = 10 pF
Output High Voltage	V _{OH}	80%			V _{DD}	I _{OH} = 3 mA
Output Low Voltage	V _{OL}			20%	V _{DD}	$I_{OL} = -3 \text{ mA}$
Input High Voltage	V _{IH}	70%	_	_	V _{DD}	Input logic high

PERFORMANCE SPECIFICATIONS

PERFORMANCE SPECIFICATIONS

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Input Low Voltage	V _{IL}	—	—	30%	V _{DD}	Input logic low
Input Pull-Up Impedance	Z _{IN}	_	300	_	kΩ	Pin 1, OE logic high or logic low, or ST logic high
Start-Up Time	t _{START}	_	_	1.5	ms	From 90% V _{DD} to valid clock output, T = +25°C
Enable/Disable Time	t _{oe}	_		1	μs	Output disable time takes up to two periods of the output waveform + 200 ns
RMS Period Jitter	t _{JITT}	_	7	_	ps	f = 27 MHz, V _{DD} = 2.5V, 2.8V, 3.0V, or 3.3V
		_	8.5			f = 27 MHz, V _{DD} = 1.8V
Cycle-to-Cycle Jitter	CC _{JITT}	_	35	60	ps	f = 27 MHz, V _{DD} = 2.0V, 2.8V, 3.0V, or 3.3V
			50	70		f = 27 MHz, V _{DD} = 1.8V

ABSOLUTE MAXIMUM RATINGS

Parameter	Minimum	Maximum
Storage Temperature	–65°C	+150°C
V _{DD}	–0.5V	+4V
Electrostatic Discharge	—	+2000V
Soldering Temperature (follow standard Pb-Free soldering guidelines)	_	+260°C

ENVIRONMENTAL COMPLIANCE

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002; (10,000g)
Mechanical Vibration	MIL-STD-883, Method 2007; Condition C 70g
Moisture Resistance	JESD22-A113; MSL-1 conditions (125°C 24 hours bake, 85%RH/85°C 168 hours, 3 Reflows 260°C)
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003

1.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 1-1.

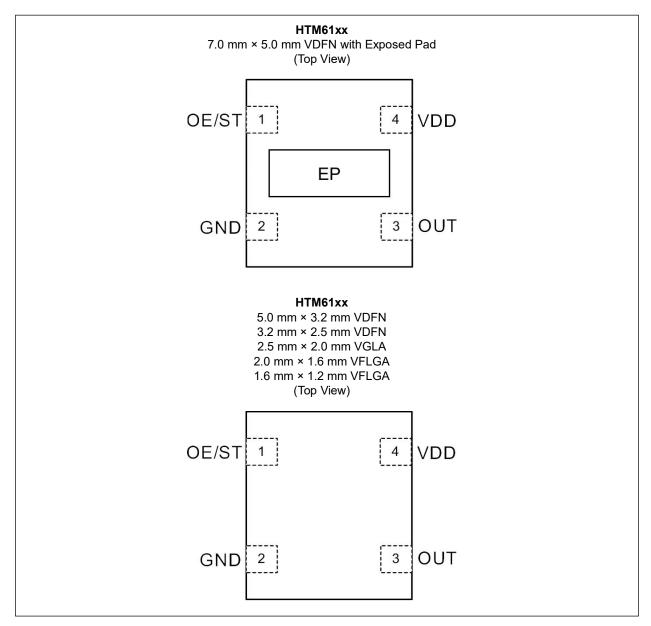
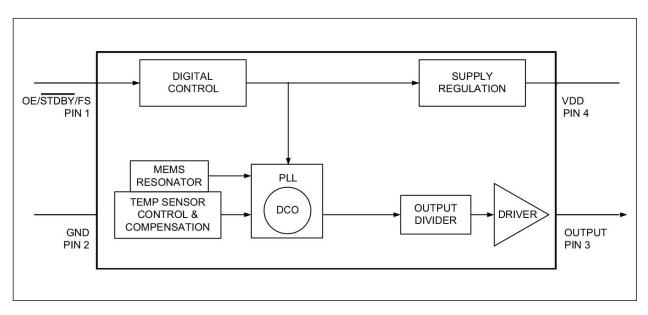


TABLE 1-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	OE/ST	Output Enable. H or Open (Note 1): Specified frequency output. L: Output is high impedance. Only output driver is disabled.
I	UE/ST	Standby. H or Open (Note 1): Specified frequency output. L: Output is low (weak pull down). Device goes to sleep mode. Supply current reduces to L _{STD} .
2	GND	Electrical ground power.
3	OUT	Oscillator output.
4	VDD	Power supply voltage.

Note 1: A pull-up resistor of <10 k Ω between OE/ST pin and V_{DD} pin is recommended in high noise environment.

2.0 FUNCTIONAL BLOCK DIAGRAM



3.0 RECOMMENDED REFLOW PROFILES FOR Pb-Free & Sn-Pb

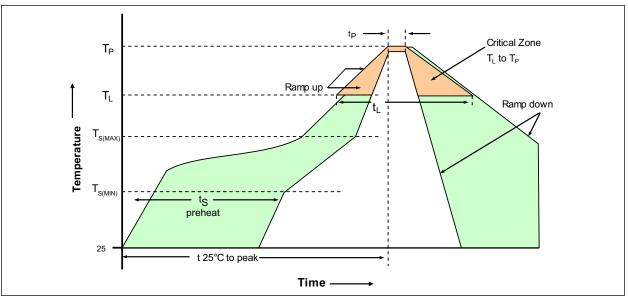


FIGURE 3-1: Reflow Profile.

TABLE 3-1: REFLOW PROFILE

Profile Feature	Symbol	Sn-Pb Assembly	Pb-Free Assembly
Average Ramp-Up Rate	T _L to T _P	3°C/second max.	3°C/second max.
Pre-Heat Minimum Temperature	T _{S(MIN)}	135°C	150°C
Pre-Heat Maximum Temperature	T _{S(MAX)}	155°C	200°C
Pre-Heat Time (from min. to max.)	t _S	60 to 90 seconds	60 to 180 seconds
T _{S(MAX)} to T _L Ramp-Up Rate	—	3°C/second max.	3°C/second max.
Low Temperature of Critical Reflow Zone	ΤL	183°C	217°C
Time Maintained Above T _L	_	40 to 60 seconds	60 to 150 seconds
Peak Temperature	Τ _Ρ	230°C max.	260°C max.
Time from 25°C to Peak Temperature	_	4 minutes max.	8 minutes max.
Time within 5°C of Actual Peak Temperature	t _P	10 to 20 seconds max.	20 to 40 seconds max.
Ramp-Down Rate	—	6°C/second max.	6°C/second max.

Note: All temperatures refer to the topside of the package, measured on the package body surface.

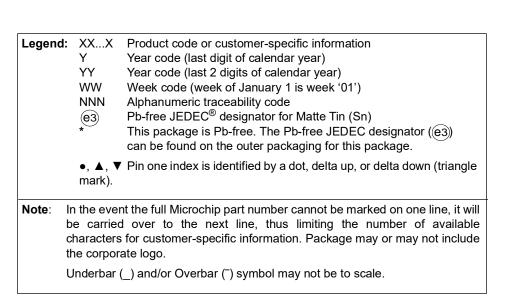
4.0 PACKAGING INFORMATION

4.1 Package Marking Information

4-Lead 7.0 mm × 5.0 mm VDFN* 4-Lead 5.0 mm × 3.2 mm VDFN* 4-Lead 2.5 mm × 2.5 mm VDFN* 4-Lead 2.5 mm × 2.0 mm VLGA* Example XXXXXXX XXXYYWW SSS 4-Lead 2.0 × 1.6 mm VFLGA*

4-Lead 1.6 × 1.2 mm VFLGA*

SSS



Example

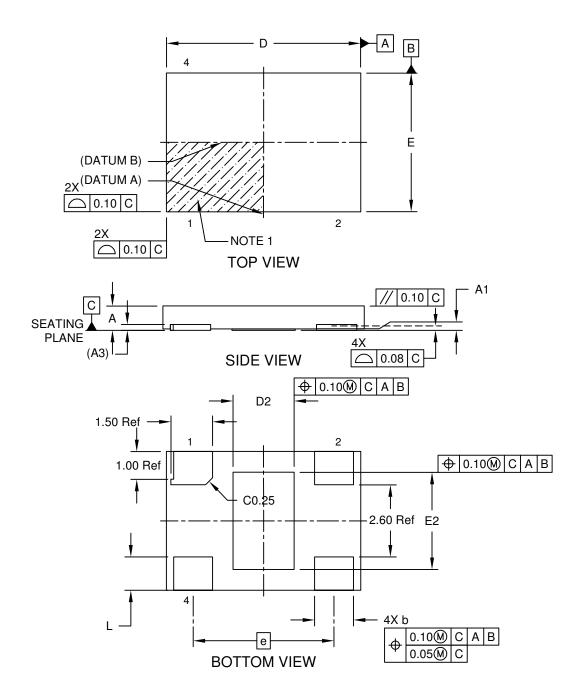
011H

326

Note: If the full seven-character YYWWNNN code cannot fit on the package, the following truncated codes are used based on the available marking space:
6 Characters = YWWNNN; 5 Characters = WWNNN; 4 Characters = WNNN; 3 Characters = NNN; 2 Characters = NN; 1 Character = N.

4-Lead Very Thin Dual Flatpack, No-Lead Package (JZA) - 7.0 mm × 5.0 mm Body [VDFN] with 2.2 mm × 3.5 mm Exposed Pad

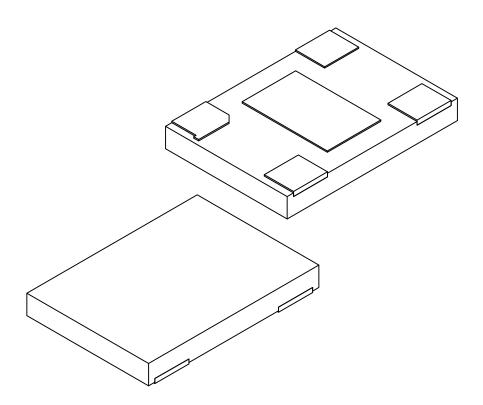
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1025 Rev A Sheet 1 of 2

4-Lead Very Thin Dual Flatpack, No-Lead Package (JZA) - 7.0 mm × 5.0 mm Body [VDFN] with 2.2 mm × 3.5 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimensior	Limits	MIN	NOM	MAX	
Number of Terminals	Ν		004		
Pitch	е		5.08 Ref		
Overall Height	Α	0.80 0.85 0.90			
Standoff	A1	0.00	-	0.05	
Terminal Thickness A3		0.203 Ref			
Overall Length	D	6.90	7.00	7.10	
Exposed Pad Length D2		2.10	2.20	2.30	
Overall Width	E	4.90	5.00	5.10	
Exposed Pad Width	E2	3.40	3.50	3.60	
Terminal Width	b	1.35	1.40	1.45	
Terminal Length	L	1.10	1.20	1.30	

Notes:

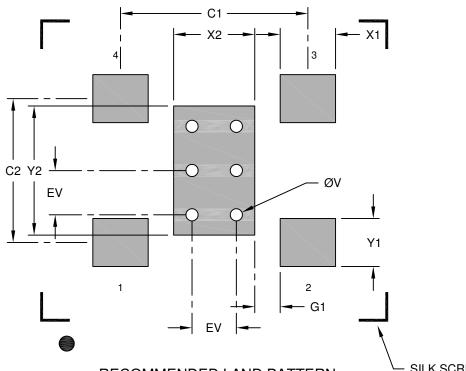
- 1. Pin 1 visual index feature may vary, but must be located within the pin 1 area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1025 Rev A Sheet 2 of 2

4-Lead Very Thin Dual Flatpack, No-Lead Package (JZA) - 7.0 mm × 5.0 mm Body [VDFN] with 2.2 mm × 3.5 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

– SILK SCREEN

	2	IILLIMETER	S	
Dimensior	n Limits	MIN	NOM	MAX
Optional Center Pad Width	X2			2.30
Optional Center Pad Length	Y2			3.60
Contact Pad Spacing	C1		5.08	
Contact Pad Spacing	C2		3.90	
Contact Pad Width (Xnn)	X1			1.50
Contact Pad Length (Xnn)	Y1			1.30
Contact Pad to Center Pad (Xnn)	G1	0.69		
Thermal Via Diameter	V		0.33	
Thermal Via Pitch	EV		1.20	

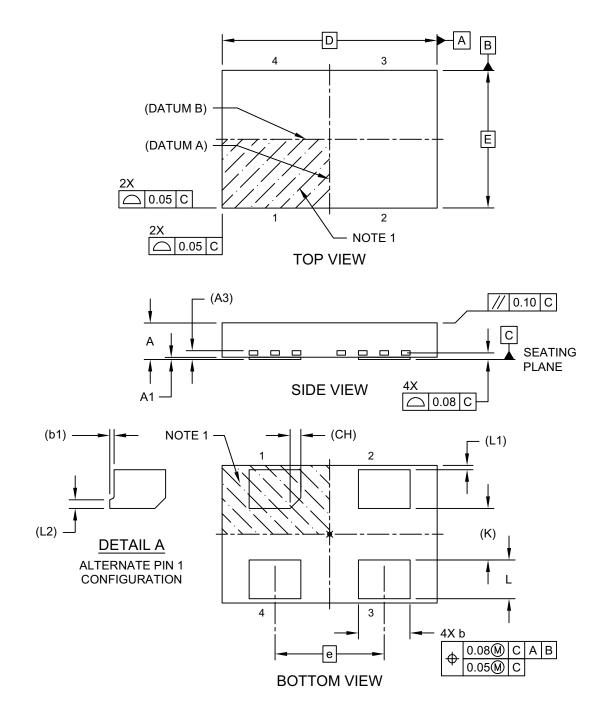
Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-3025 Rev A

4-Lead Very Thin Plastic Dual Flat, No-Lead Package (H6A) - 5.0 mm × 3.2 mm Body [VDFN]

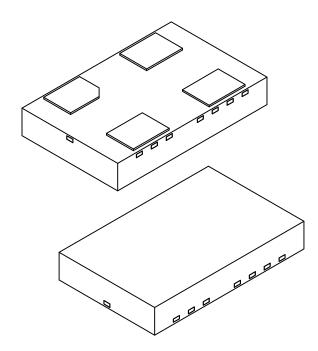
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1008 Rev A Sheet 1 of 2

4-Lead Very Thin Plastic Dual Flat, No-Lead Package (H6A) - 5.0 mm × 3.2 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S	
Dimension	Dimension Limits		NOM	MAX	
Number of Terminals	mber of Terminals N		4		
Pitch	е		2.54 BSC		
Overall Height	А	0.80	0.85	0.90	
Standoff	A1	0.00	0.02	0.05	
Terminal Thickness	A3	0.20 REF			
Overall Length	D	5.00 BSC			
Overall Width	E	3.20 BSC			
Terminal Width	b	1.15 1.20 1.25			
Terminal 1 Tab	b1		0.10 REF		
Terminal Length	L	0.80	0.90	1.00	
Terminal Pull Back	L1	0.10 REF			
Terminal 1 Tab	L2	0.20 REF			
Terminal 1 Chamfer	СН	0.25 REF			
Terminal Spacing	K	1.20 REF			

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

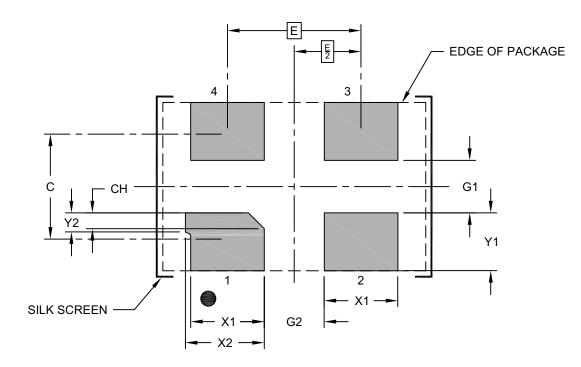
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1008 Rev A Sheet 2 of 2

4-Lead Very Thin Plastic Dual Flat, No-Lead Package (H6A) - 5.0 mm × 3.2 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Ν	IILLIMETER	S	
Dimension	Dimension Limits			MAX
Contact Pitch	E			
Contact Pad Spacing	С		2.00	
Contact Pad Width (X4)	X1			1.40
Contact Pad Width	X2			1.50
Contact Pad Length (X4)	Y1			1.10
Contact Pad Tab Length	Y2			0.36
Contact Pad to Center Pad (X2)	G1	1.00		
Contact Pad to Contact Pad (X2)	G2	1.14		
Terminal 1 Contact Pad Chamfer	СН		0.30	

Notes:

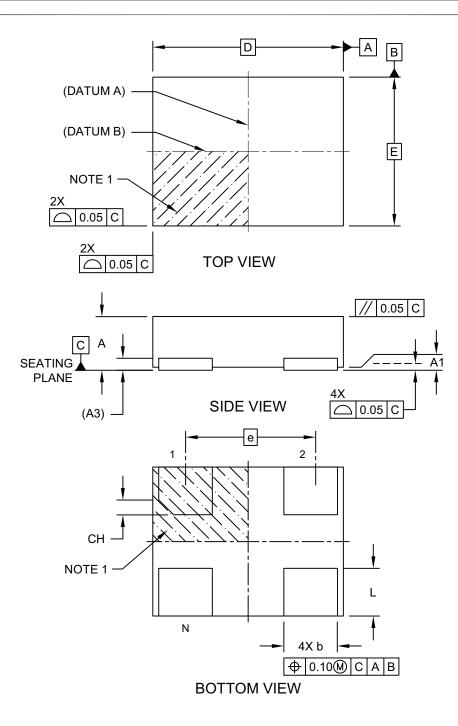
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3008 Rev A

4-Lead Very Thin Plastic Dual Flatpack No-Lead (H4A) - 3.2 mm × 2.5 mm Body [VDFN]

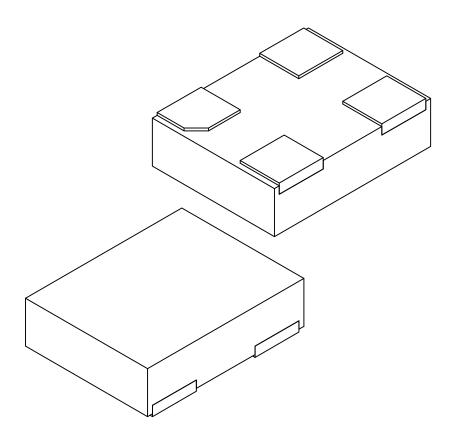
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1006 Rev B Sheet 1 of 2

4-Lead Very Thin Plastic Dual Flatpack No-Lead (H4A) - 3.2 mm × 2.5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S
Dimension	Limits	MIN	NOM	MAX
Number of Terminals	N		4	
Pitch	е	2.10 BSC		
Overall Height	Α	0.80 0.85 0.90		
Standoff	A1	0.00	0.02	0.05
Overall Length	D	3.20 BSC		
Overall Width	E		2.50 BSC	
Terminal Width	b	0.85 0.90 0.95		
Terminal Length	L	0.70 0.80 0.90		0.90
Terminal 1 Index Chamfer	СН	CH 0.25 REF		

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

3. Dimensioning and tolerancing per ASME Y14.5M

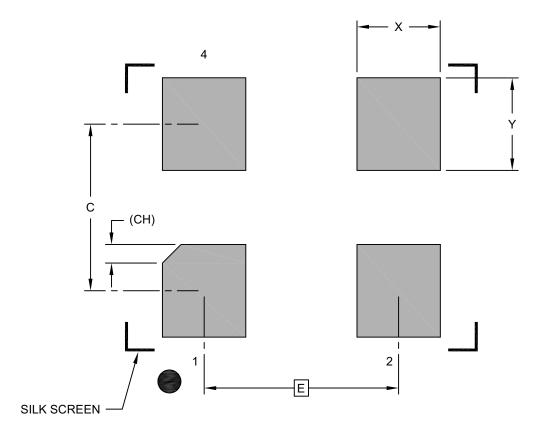
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1006 Rev B Sheet 2 of 2

4-Lead Very Thin Plastic Dual Flatpack No-Lead (H4A) - 3.2 mm × 2.5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	E	2.10 BSC		
Contact Pad Spacing	С		1.80	
Contact Pad Width (Xnn)	Х			0.90
Contact Pad Length (Xnn)	Y			1.00
Contact Pad Length (Xnn)	СН		0.20 REF	

Notes:

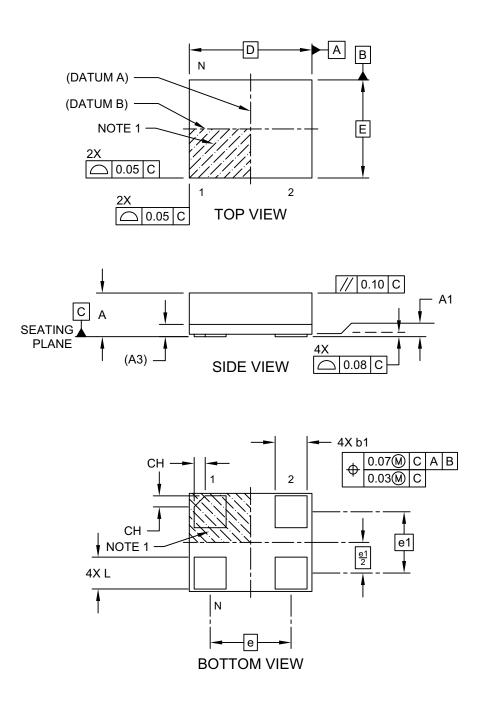
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-3006 Rev B

4-Lead Very Thin Land Grid Array (AUA) - 2.5 mm × 2.0 mm Body [VLGA]

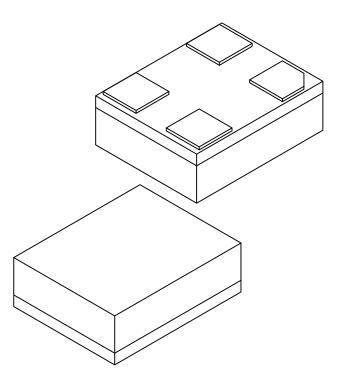
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1202B Sheet 1 of 2

4-Lead Very Thin Land Grid Array (AUA) - 2.5 mm × 2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Number of Terminals	Ν		4	
Terminal Pitch	е		1.65 BSC	
Terminal Pitch	e1	1.25 BSC		
Overall Height	Α	0.79 0.84 0.89		
Standoff	A1	0.00 0.02 0.03		
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D	2.50 BSC		
Overall Width	Ш	2.00 BSC		
Terminal Width	b1	0.60	0.65	0.70
Terminal Length	L	0.60	0.65	0.70
Terminal 1 Index Chamfer	СН	H - 0.225 -		

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

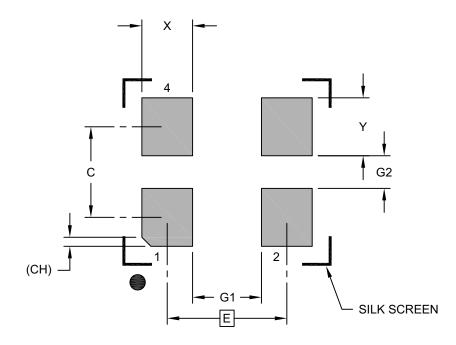
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1202B Sheet 2 of 2

4-Lead Very Thin Land Grid Array (AUA) - 2.5 mm × 2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	E	1.65 BSC		
Contact Spacing	С		1.25	
Contact Width (X4)	Х			0.70
Contact Pad Length (X4) Y				0.80
Space Between Contacts (X2)	G1	0.95		
Space Between Contacts (X2)	G2	0.45		
Contact 1 Index Chamfer	СН	0.13 X 45° REF		

Notes:

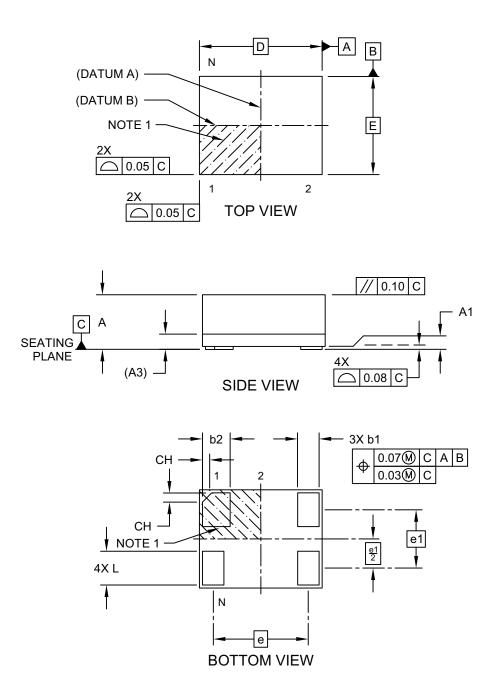
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3202B

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0 mm × 1.6 mm Body [VFLGA]

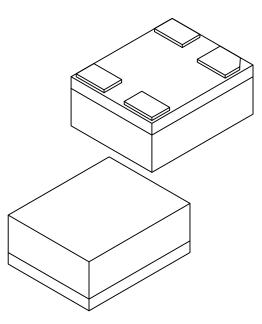
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1200 Rev D Sheet 1 of 2

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0 mm × 1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Dimension Limits			MAX	
Number of Terminals	Ν		4		
Terminal Pitch	е		1.55 BSC		
Terminal Pitch	e1	0.95 BSC			
Overall Height	Α	0.79	0.84	0.89	
Standoff	A1	0.00	0.02	0.05	
Substrate Thickness (with Terminals)	A3	0.20 REF			
Overall Length	D	2.00 BSC			
Overall Width	Е	1.60 BSC			
Terminal Width	b1	0.30	0.35	0.40	
Terminal Width	b2	0.40	0.45	0.50	
Terminal Length	L	0.50	0.55	0.60	
Terminal 1 Index Chamfer	СН	-	0.15	-	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

3. Dimensioning and tolerancing per ASME Y14.5M

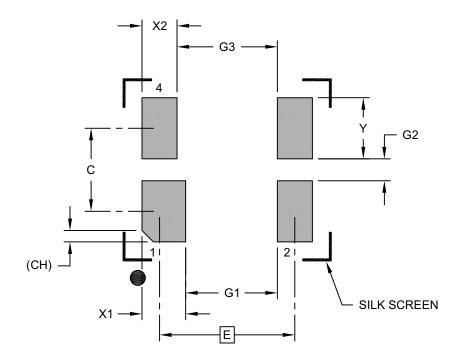
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1200 Rev D Sheet 2 of 2

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0 mm × 1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	E	1.55 BSC		
Contact Spacing	С		0.95	
Contact Width	X1			0.50
Contact Width (X3)	X2			0.40
Contact Pad Length (X4)	Y			0.70
Space Between Contacts	G1	1.05		
Space Between Contacts (X2)	G2	0.25		
Space Between Contacts	G3	1.15		
Contact 1 Index Chamfer	СН	0.13 X 45° REF		

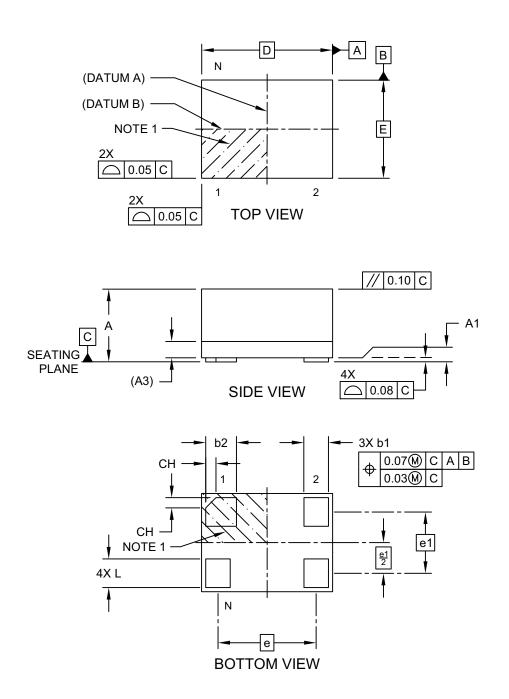
Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. The value in parenthesis, next to the item description is a unit multiplier.

Microchip Technology Drawing C04-3200 Rev D

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6 mm × 1.2 mm Body [VFLGA]

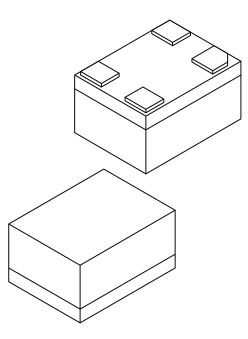
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-1199B Sheet 1 of 2

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6 mm × 1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits			MAX
Number of Terminals	Ν		4	
Terminal Pitch	е		1.20 BSC	
Terminal Pitch	e1	0.75 BSC		
Overall Height	Α	0.79 0.84 0.89		
Standoff	A1	0.00 0.02 0.05		
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D	1.60 BSC		
Overall Width	Е	1.20 BSC		
Terminal Width	b1	0.25	0.30	0.35
Terminal Width	b2	0.325	0.375	0.425
Terminal Length	L	0.30	0.35	0.40
Terminal 1 Index Chamfer	СН	-	0.125	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

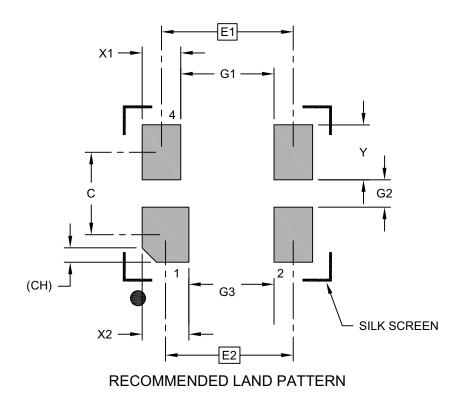
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1199B Sheet 2 of 2

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6 mm × 1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E1	1.20 BSC		
Contact Pitch	E2		1.16 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2			0.43
Contact Pad Length (X4)	Y			0.50
Space Between Contacts	G1	0.85		
Space Between Contacts (X2)	G2	0.25		
Space Between Contacts	G3	0.77		
Contact 1 Index Chamfer	СН	0.13 X 45° REF		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. The value in parenthesis, next to the item description is a unit multiplier.

Microchip Technology Drawing C04-3199B

APPENDIX A: REVISION HISTORY

Revision A (March 2023)

• Initial release of HTM61xx as Microchip data sheet DS20006766A.

Revision B (February 2025)

• Updated package quantities between option J and option M in the Product Identification System section and the Minimum Order Quantity table.

HTM61XX

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

			X	X	X	X	- <u>xxx.xxxx</u> <u>-xxxKxxx</u>	[X] [X_XXXX]	
eature Pin	Output D	rive Strength	Package	Temperature Rar	nge Stability	Revision	Frequency	Media Type	
HTM61			itary Tempera	ture MEMS	•				
0	= Enable	/Disable			a) HTM6101HA3 125.0000	Pin 4-L	, Standard Output ead 1.6 mm × 1.2	Drive Strength, mm VFLGA	
1	= Standb	у				Rai B, 1	Package, -40°C to +125°C Tem Range, ±20 ppm Stability, Revis B, 125.0000 MHz Frequency, C Tape/pop-TR		
1	= Standa	rd			b) HTM6111AL2E 024.0000	B- HTI Sta	M61xx, Standby I Indard Output Dri	/e Strength, 4-	
A B C	= 4-Lead	5.0 mm × 3.2	mm VDFN			±25 024	5 ppm Stability, Re 1.0000 MHz Frequ	evision B,	
J M H	= 4-Lead	2.0 mm × 1.6	mm VFLGA		c) HTM6101BI1E 026.0000	- HTI Pin	M61xx, Enable/D , Standard Outpu	Drive Strength,	
A	= -40°C	to +105°C				Pao Rai B, (Package, –40°C to +85°C Tel Range, ±50 ppm Stability, Re B, 026.0000 MHz Frequency,		
E					d) HTM6111CE3 033.3333	B- HTI Sta	M61xx, Standby I Indard Output Dri	ve Strength, 4-	
1 2 3	= ±25 pp	m				age ±20 033	e, –20°C to +70°C) ppm Stability, Ro 3.3333 MHz Frequ	Temp. Range, evision B,	
В			_		e) HTM6101JA28 025.0000	Pin 4-L	, Standard Output ead 2.5 mm × 2.0	Drive Strength	
		and 100.00 efined Freque	000 MHz ncy Between (Rai B, (nge, ±25 ppm Sta 025.0000 MHz Fr	bility, Revision	
_	= Tape ai = Tin Lea	nd Reel ad (SnPb) Sold	er Dip	ormation.	f) HTM6111ML1E 016K000	Sta Lea Pao Rai B, 2	ndard Output Dri ad 2.0 mm × 1.6 r ckage, –40°C to + nge, ±20 ppm Sta 125.000 MHz Fre	ve Strength, 4- nm VFLGA 105°C Temp. bility, Revision	
(4-Lead 1.6 Tape and Re description. printed on th	mm × 1.2 m eel identifier This identifie ne device pa	m VFLGA). only appears in er is used for of ckage. Check	n the catalog p rdering purpos with your Micro	part number ses and is not pochip Sales	g) HTM6101HA3 100.0000T	Pin 4-L Pao Rai B, 2	, Standard Outpur ead 1.6 mm × 1.2 ckage, –40°C to + nge, ±20 ppm Sta 100.0000 MHz Fr	Drive Strength mm VFLGA 125°C Temp. bility, Revision	
						B Pin 4-L Pao Rai B, (, Standard Outpu ead 3.2 mm × 2.5 ckage, –40°C to + nge, ±20 ppm Sta 050.0000 MHz Fr	Drive Strength mm VDFN 125°C Temp. bility, Revision	
	HTM61 0 1 1 A B C J M H H A L I E 1 2 3 B XXX.XXXX XXXXX XXXXXX XXXXXX XXXXXXXX	HTM61 = High Te Oscillat 0 = Enable 1 = Standb 1 = Standb 1 = Standa A = 4-Lead B = 4-Lead C = 4-Lead C = 4-Lead M = 4-Lead H = 4-Lead H = 4-Lead H = 4-Lead H = 4-Lead C = -40°C L = -40°C E = -20°C 1 = ± 50 pp 2 = ± 25 pp 3 = ± 20 pp B = Revision xxx.xxx = User-D xxxKxxx = User-D xxxKxxx = User-D xxxKxxx = User-D xxxKxxx = User-D The SnPb solder dip me (4-Lead 1.6 mm × 1.2 m Tape and Reel identifier description. This identifier printed on the device par	HTM61 = High Temperature MilOscillator 0 = Enable/Disable 1 = Standby 1 = Standard A = 4-Lead 7.0 mm × 5.0 B = 4-Lead 5.0 mm × 3.2 C = 4-Lead 3.2 mm × 2.5 J = 4-Lead 2.5 mm × 2.0 M = 4-Lead 2.0 mm × 1.2 A = -40°C to +125°C L = -40°C to +125°C L = -40°C to +105°C I = -40°C to +85°C E = -20°C to +70°C 1 = ±50 ppm 2 = ±25 ppm 3 = ±20 ppm B = Revision B xxx.xxxx = User-Defined Frequent and 100.00 xxxKxxx = User-Defined Frequent and 999.99	HTM61 = High Temperature Military Temperat Oscillator 0 = Enable/Disable 1 = Standby 1 = Standby 1 = Standby 1 = Standard A = 4-Lead 7.0 mm × 5.0 mm VDFN B 1 = Standard A = 4-Lead 7.0 mm × 5.0 mm VDFN C B = 4-Lead 3.0 mm × 3.2 mm VDFN C J = 4-Lead 2.0 mm × 1.2 mm VLGA M H = 4-Lead 2.0 mm × 1.6 mm VFLGA H = 4-Lead 1.6 mm × 1.2 mm VFLGA A = -40°C to +125°C L L = -40°C to +125°C L L = -40°C to +85°C E E = -20°C to +70°C 1 = ±50 ppm 3 = 2 = ±25 ppm 3 = B = Revision B xxx.xxxx = User-Defined Frequency Between C and 100.0000 MHz xxxKxxx = User-Defined Frequency Between C and 999.999 kHz	HTM61 = High Temperature Military Temperature MEMSOscillator 0 = Enable/Disable 1 = Standby 1 = Standard A = 4-Lead 7.0 mm × 5.0 mm VDFN B = 4-Lead 7.0 mm × 5.0 mm VDFN B = 4-Lead 7.0 mm × 5.0 mm VDFN C = 4-Lead 3.2 mm × 2.5 mm VDFN J = 4-Lead 2.5 mm × 2.0 mm VLGA M = 4-Lead 2.16 mm × 1.2 mm VFLGA H = 4-Lead 1.6 mm × 1.2 mm VFLGA A = -40°C to +125°C L = -40°C to +125°C L = -40°C to +05°C I = ±50 ppm 2 = ±25 ppm 3 = ±20 ppm B = Revision B xxx.xxxx = User-Defined Frequency Between 001.0000 MHz and 100.0000 MHz xxxKxxx = User-Defined Frequency Between 003.500 kHz and 999.999 kHz <pre></pre>	HTM61 High Temperature Military Temperature MEMS 0 = Enable/Disable 1 = Standby 1 = Standard 1 = Standard 1 = Standard 2 = 4-Lead 7.0 mm × 5.0 mm VDFN B = 4-Lead 5.0 mm × 5.0 mm VDFN C = 4-Lead 2.0 mm × 5.0 mm VDFN J = 4-Lead 2.0 mm × 2.0 mm VLGA M = 4-Lead 2.0 mm × 2.0 mm VLGA M = 4-Lead 2.0 mm × 1.0 mm VFLGA H = 4-Lead 1.0 mm × 1.0 mm VFLGA H = 4-Lead 1.0 mm × 1.0 mm VFLGA A = -40°C to +125°C L = -40°C to +105°C I = 450 ppm 2 = 125 ppm 3 = ±20 ppm B = Revision B xxx.xxxx User-Defined Frequency Between 001.0000 MHz and 199.999 kHz 1) HTM6101JA2E 016K000 xxt.xxxx User-Defined Frequency Between 003.500 kHz and 999.999 kHz 1) HTM6101HA3 10.0000 T 1) HTM6101HA3 10.0000 T 1) HTM6101HA3 10.0000 T 1) HTM6101HA3 10.0000 T </td <td>HTM61 = High Temperature Military Temperature MEMSOscillator $HTM61 = High Temperature Military Temperature MEMSOscillator 0 = Enable/Disable 1 = Standby 1 = Standard 1 = A-4Lead 7.0 mm × 5.0 mm VDFN B = 4-Lead 5.0 mm × 3.2 mm VDFN J = 4-Lead 2.5 mm × 2.0 mm VLGA A = -40°C to +125°C L = -40°C to +125°C L = -40°C to +125°C L = -40°C to +155°C E = -20°C to +70°C 3 = ±20 ppm 3 = ±20 ppm B = Revision B xox.xoxx = User-Defined Frequency Between 001.0000 MHz and 100.0000 MHz xoxKoxx = User-Defined Frequency Between 001.0000 MHz and 100.0000 MHz xoxKoxx = User-Defined Frequency Between 001.0000 MHz and 999.999 kHz () HTM6101JA2B- The SnPb solder dip media type is not supported for Package H (-Lead 1.6 mm × 1.2 mm VFLGA). 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MINIMUM ORDER QUANTITY

Package or Media Type	Pieces	Notes
Package A	50 pieces per tube	100 piece minimum order
Package B	72 pieces per tube	144 piece minimum order
Package C	110 pieces per tube	110 piece minimum order
Package J	140 pieces per tube	140 piece minimum order
Package M	100 pieces per bag	100 piece minimum order
Package H	100 pieces per bag	100 piece minimum order
Tape and Reel	1000 pieces per reel	1000 piece minimum order
SnPb Solder Dip	500 pieces per reel	500 piece minimum order

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